



#### **50V NPN LOW SATURATION TRANSISTOR**

#### **Features**

- BV<sub>CEO</sub> > 50V
- I<sub>C</sub> = 4A Continuous Collector Current
- Low Saturation Voltage (100mV Max @1A)
- R<sub>SAT</sub> = 68mΩ for a Low Equivalent On-Resistance
- h<sub>FE</sub> Specified up to 6A for High Current Gain Hold Up
- Low Profile 0.6mm High Package for Thin Applications
- R<sub>θJA</sub> Efficient, 60% Lower than SOT23
- 4mm<sup>2</sup> Footprint, 50% Smaller than SOT23
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (ZXTN619MAQ)

### **Mechanical Data**

- Case: U-DFN2020-3
- Nominal Package Height: 0.6mm
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu, Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.01 grams (Approximate)

### **Applications**

- MOSFET Gate Driving
- DC-DC Converters
- Charging Circuits
- Motor Control
- Power Switches

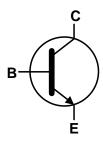
#### U-DFN2020-3 (Type B)



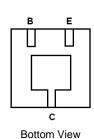




**Bottom View** 



Device Symbol



Pin-Out

March 2019

© Diodes Incorporated

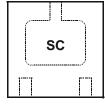
### Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXTN619MATA	SC	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



Top View

SC = Product Type Marking code



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Parameter		Symbol	Limit	Unit	
Collector-Base Voltage		V <sub>CBO</sub>	100		
Collector-Emitter Voltage		V <sub>CEO</sub>	50	V	
Emitter-Base Voltage		V <sub>EBO</sub>	7		
Peak Pulse Current		Ісм	6		
Continuous Collector Current (Note 5) (Note 6)		1	4		
		IC	4.3	A	
Base Current		I <sub>B</sub>	1		

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)		1.5 12	W mW/°C	
Linear Derating Factor	(Note 6)	P <sub>D</sub>	2.45 19.6		
Thermal Resistance, Junction to Ambient	(Note 5)	D	83		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	51	°C/W	
Thermal Resistance, Junction to Lead (Note 7)		$R_{ heta JL}$	16.8		
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

# ESD Ratings (Note 8)

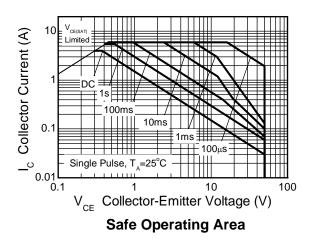
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

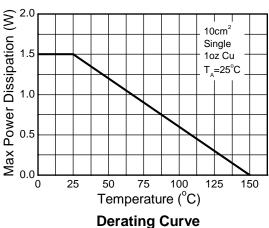
Notes:

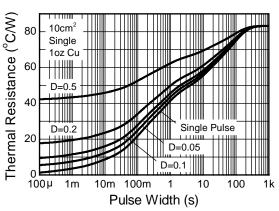
- 5. For a device mounted with the exposed collector pad on 31mm x 31mm (10cm²) 1oz copper that is on a single sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state. The entire exposed collector pad is attached to the heatsink.
  6. Same as Note 5, except the device is measured at t ≤ 5s.
  7. Thermal resistance from junction to solder-point (on the exposed collector pad).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

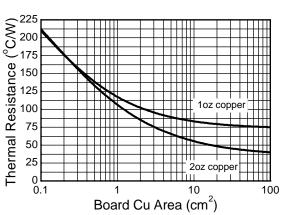


# **Thermal Characteristics and Derating Information**



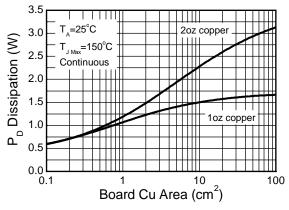






**Transient Thermal Impedance** 

Thermal Resistance v Board Area



**Power Dissipation v Board Area** 



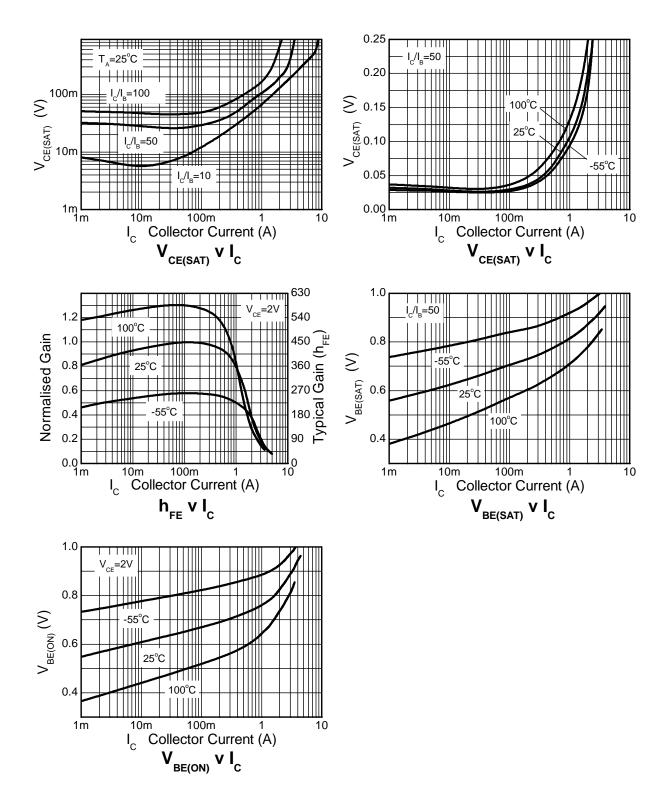
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	100	190	_	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	50	65	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.2	_	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CBO</sub>	_	_	100	nA	V <sub>CB</sub> = 80V
Emitter Cutoff Current	I <sub>EBO</sub>	_	_	20	nA	V <sub>EB</sub> = 6V
Collector Emitter Cutoff Current	I <sub>CES</sub>	_	_	100	nA	V <sub>CES</sub> = 40V
Static Forward Current Transfer Ratio (Note 9)	h <sub>FE</sub>	200 300 200 100	400 450 400 225 40	_ _ _ _	_	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 2V I <sub>C</sub> = 200mA, V <sub>CE</sub> = 2V I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V I <sub>C</sub> = 2A, V <sub>CE</sub> = 2V I <sub>C</sub> = 6A, V <sub>CE</sub> = 2V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(SAT)</sub>		10 70 145 150 225 270	20 100 200 220 300 320	mV	$\begin{split} &I_{C}=0.1A,\ I_{B}=10mA\\ &I_{C}=1A,\ I_{B}=50mA\\ &I_{C}=1A,\ I_{B}=10mA\\ &I_{C}=2A,\ I_{B}=50mA\\ &I_{C}=3A,\ I_{B}=100mA\\ &I_{C}=4A,\ I_{B}=200mA \end{split}$
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(ON)}$	_	0.94	1.00	V	$I_C = 4A$ , $V_{CE} = 2V$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(SAT)</sub>	_	1.00	1.07	V	$I_C = 4A$ , $I_B = 200mA$
Output Capacitance	C <sub>OBO</sub>	_	12	20	pF	V <sub>CB</sub> = 10V, f = 1MHz
Transition Frequency	f <sub>T</sub>	100	165	_	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA, f = 100MHz
Turn-On Time	t <sub>ON</sub>	_	170	_	ns	V <sub>CC</sub> = 10V, I <sub>C</sub> = 1A
Turn-Off Time	t <sub>OFF</sub>	_	750	_	ns	$I_{B1} = -I_{B2} = 10mA$

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

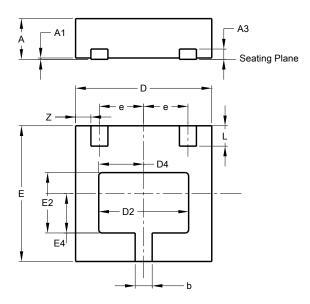




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2020-3 (Type B)

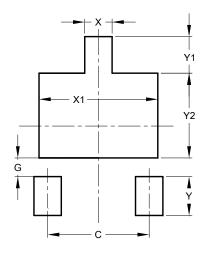


U-DFN2020-3					
(Type B)					
Dim	Min	Max	Тур		
Α	0.57	0.63	0.60		
A1	0.00	0.05	0.02		
A3			0.152		
b	0.20	0.30	0.25		
D	1.950	2.075	2.00		
D2	1.22	1.42	1.32		
D4	0.56	0.76	0.66		
Е	1.950	2.075	2.00		
E2	0.79	0.99	0.89		
E4	0.48	0.68	0.58		
е	_	_	0.65		
٦	0.25	0.35	0.30		
Z			0.225		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### U-DFN2020-3 (Type B)



Dimensions	Value		
Dilliensions	(in mm)		
С	1.300		
G	0.240		
X	0.350		
X1	1.520		
Y	0.500		
Y1	0.470		
Y2	1 090		



#### **IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2019, Diodes Incorporated

www.diodes.com